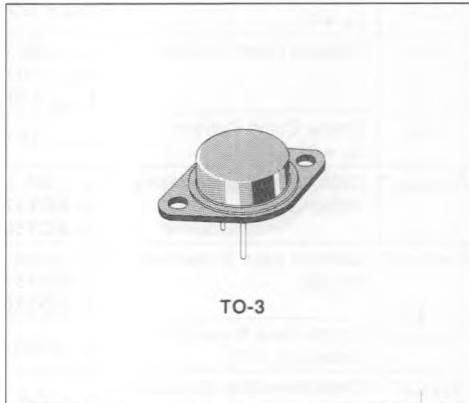


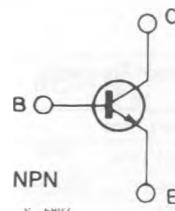
HIGH CURRENT,  
 HIGH SPEED, HIGH POWER TRANSISTORS

**DESCRIPTION**

The BDY57 and BDY58 are silicon multiepitaxial planar NPN transistors in Jedec TO-3 metal case, intended for use in switching and linear applications in military and industrial equipment.



TO-3

**INTERNAL SCHEMATIC DIAGRAM**


S- 6897

**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value		Unit
		BDY57	BDY58	
$V_{CBO}$	Collector-base Voltage ( $I_E = 0$ )	120	160	V
$V_{CEO}$	Collector-emitter Voltage ( $I_B = 0$ )	80	125	V
$V_{EBO}$	Emitter-base Voltage ( $I_C = 0$ )	10		V
$I_C$	Collector Current	25		A
$I_B$	Base Current	6		A
$P_{tot}$	Total Power Dissipation at $T_{case} \leq 25^\circ\text{C}$	175		W
$T_{stg}$	Storage Temperature	- 65 to 200		°C
$T_J$	Junction Temperature	200		°C

## THERMAL DATA

$R_{th\ j-case}$	Thermal Resistance Junction-case	Max	1	°C/W
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ELECTRICAL CHARACTERISTICS ( $T_{case} = 25^\circ C$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{CBO}$	Collector Cutoff Current ( $I_E = 0$ )	$V_{CB} = 120\ V$			1	mA
$I_{CE(sus)}$	Collector-emitter Sustaining Voltage	$V_{CE} = 80\ V$ $R_{BE} = 10\ \Omega$ $T_{case} = 100^\circ C$			10	mA
$I_{EBO}$	Emitter Cutoff Current ( $I_C = 0$ )	$V_{EB} = 10\ V$			0.5	mA
$V_{CEO(sus)}^*$	Collector-emitter Sustaining Voltage	$I_C = 100\ mA$ for BDY57 for BDY58	80	125		V
$V_{(BR)CBO}^*$	Collector-base Breakdown Voltage	$I_C = 5\ mA$ for BDY57 for BDY58	120	160		V
$V_{(BR)EBO}^*$	Emitter-base Breakdown Voltage ( $I_C = 0$ )	$I_E = 5\ mA$	10			V
$V_{CE(sat)}^*$	Collector-emitter Saturation Voltage	$I_C = 10\ A$	$I_B = 1\ A$	0.5	1.4	V
$V_{BE(sat)}^*$	Base-emitter Saturation Voltage	$I_C = 10\ A$	$I_B = 1\ A$		1.4	V
$\beta_{FE}^*$	DC Current Gain	$I_C = 10\ A$ $I_C = 20\ A$ $T_{case} = -30^\circ C$ $I_C = 10\ A$	$V_{CE} = 4\ V$ $V_{CE} = 4\ V$ $V_{CE} = 4\ V$	20	15	60
$f_T$	Transition Frequency	$I_C = 1\ A$ $f = 10\ MHz$	$V_{CE} = 15\ V$	7		MHz
$t_{on}$	Turn-on Time	$I_C = 15\ A$	$I_{B1} = 1.5\ A$		1	$\mu s$
$t_{off}$	Turn-off Time	$I_C = 15\ A$	$I_{B1} = -I_{B2} = 1.5\ A$		2	$\mu s$
	Clamped E <sub>s/b</sub> Collector Current	$V_{(clamp)} = 125\ V$ $L = 500\ \mu H$		15		A

\* Pulsed : pulse duration = 300  $\mu s$ , duty cycle  $\leq 2\%$ .